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TECHNICAL REPORT



IEC nanoelectronics standardization roadmap

INTERNATIONAL ELECTROTECHNICAL COMMISSION

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CONTENTS

FΟ	REWOR	RD		4
INT	RODUC	CTION		6
1	Scope			7
2	Backg	round		8
	2.1	General.		8
	2.2	Classific	ation of nanotechnology	9
		2.2.1	General	9
		2.2.2	Nanomaterials	9
		2.2.3	Nanoscale devices	9
		2.2.4	Nano-biotechnology	9
		2.2.5	Nanofabrication process – Equipment – Measurement	9
3	Curre	nt status an	d prospects	9
	3.1	Related	markets	9
	3.2	Technolo	ogy development directions for nanomaterials	10
		3.2.1	General	10
		3.2.2	World leading group status	11
		3.2.3	Nanopore materials	
		3.2.4	Nanocomposite materials	
	3.3	Overall t	echnology status and prospects of nanoelectronic devices	12
4	Nanor		chnology, scenario and standardization roadmap	
	4.1	Technolo	ogy	13
		4.1.1	Classification of nanomaterials	
		4.1.2	Standardization items of zero dimensional nanomaterials	14
		4.1.3	Standardization items of one-dimensional nanomaterials	
		4.1.4	Standardization items of two-dimensional nanomaterials	
		4.1.5	Standardization items of three-dimensional nanomaterial	
	4.2		DS	
		4.2.1	Scenario for nanoparticles (or nanopowders)	
		4.2.2	Scenario for quantum dots	
		4.2.3	Scenario for carbon nanotubes	
		4.2.4	Scenario for nanowires	
		4.2.5	Scenario for nanostructured thin films	_
		4.2.6	Scenario for sheet resistance characterization of CNT films	
		4.2.7	Scenario for wear resistance and exposure test of CNT films	
		4.2.8 4.2.9	Scenario for thermal characterization of CNT films	
		4.2.9 4.2.10	Scenario for graphene	
		4.2.10	Scenario for nanocomposite materials	
	4.3		p of standardization of nanomaterials (2009-2020)	
5			evices technology, scenario and standardization roadmap	
5				
	5.1	5.1.1	Nancasala non valetile memory devises	
		5.1.1 5.1.2	Nanoscale non-volatile memory devices New nanomaterial or new nanostructure for nanoelectronic	24
		ე. 1.∠	devicesdevices	24
		5.1.3	Three-dimensional nanoscale transistors	
		5.1.4	Single electron transistors	
		5.1.5	Nanoscale logic devices	
			•	

	5.1.6	Carbon interconnects	25
	5.1.7	Nanoscale magnetic devices	25
	5.1.8	Molecular devices	25
5.2	Scenario)	25
	5.2.1	Scenario for nanoscale non-volatile memory devices	
	5.2.2	Scenario for nanostructure electronic materials	26
	5.2.3	Scenario for nanoscale interconnects (CNT)	
	5.2.4	Scenario for one-dimensional nanoscale transistors	
	5.2.5	Scenario for three-dimensional nanoscale transistors	
	5.2.6	Scenario for single electron transistors	28
	5.2.7	Scenario for key control characteristics of nanoscale logic devices	20
	5.2.8	Scenario for molecular devices	
5.3		dization roadmap of nanoelectronic devices (2009-2020)	
Bibliograph	y		02
Figure 1 – I	Roadman f	ormat	6
_		es and related products	
_		of product, technology and standardization roadmaps	9
		G3 roadmap for standardization of nanomaterials:	11
	_	resistance of 50 nm-diameter vias dependent on the filling rate of	
CNTs in a v	ia hole for	1 nm-diameter SWNT, 3 nm-diameter 3-walled MWNT, and	
5 nm-diame	eter 6-walle	ed MWNT	27
Figure 6 – I	Roadmap f	or standardization of nanomaterials (2009-2020)	30
Figure 7 – I	Roadmap f	or standardization of nanoelectronic devices (2009-2020)	31
Table 1 – C	ategories a	and detail potential products	7
		on of nanomaterials	
		tics to be considered in developing standards for nanoparticles	
		tics to be considered in developing standards for quantum dot	
		tics to be considered in developing standards for CNT	
Table 6 – C	haracterist	tics to be considered in developing standards for nanowires	16
		tics to be considered in developing standards for nanostructured	40
			16
		tics to be considered in developing standards for nanostructured	17
		tics to be considered in developing standards for nanopores	1/
		stics to be considered in developing standards for ials	10
•			
rable TT –	iviaurix for (graphene characterization	∠3

-4-

INTERNATIONAL ELECTROTECHNICAL COMMISSION

IEC NANOELECTRONICS STANDARDIZATION ROADMAP

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IEC 62834, which is a technical report, has been prepared by IEC technical committee 113: Nanotechnology standardization for electrical and electronic products and systems.

The text of this technical report is based on the following documents:

Enquiry draft	Report on voting	
113/161/DTR	113/161/DTR 113/197/RVC	

Full information on the voting for the approval of this technical report can be found in the report on voting indicated in the above table.

This publication has been drafted in accordance with the ISO/IEC Directives, Part 2.

The committee has decided that the contents of this publication will remain unchanged until the stability date indicated on the IEC web site under "http://webstore.iec.ch" in the data related to the specific publication. At this date, the publication will be

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- 5 -

- · reconfirmed,
- · withdrawn,
- · replaced by a revised edition, or
- · amended.

A bilingual version of this publication may be issued at a later date.

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INTRODUCTION

In IEC TC113 a survey on nano-electrotechnical standardization needs was initiated by the National Institute of Standards and Technology (NIST) in the USA to establish a strategy of standardization priorities regarding the nanoelectronics area. A TC 113 Project Team was then organized to build a "Nanoelectronics standards roadmap". This document covers nanoscale devices and nanomaterials which will be in the market or are already commercialized for nanoelectronic applications. When selecting the devices and materials to be included in the roadmap, the Project Team considered their market size and the period of time needed for their technology development. Because most of the experts in TC 113 are from an electronics background, the first version (Part A) of this roadmap covers electronics and ICT (information and communication technology) rather than energy or convergence technologies.

Regarding nanomaterials, roadmaps for carbon nanotubes (CNT), graphene, nanofibres, nanoparticles and quantum dots were established. For each material there are several detailed items that need to be standardized, including physical properties and characterization methods. Some of such standards are already under development in TC 113, such as IEC 62565-2-1 and IEC 62569.

In the nanoelectronics device roadmap, nanoscale contacts, CNT interconnects, three-dimensional nanotransistors, nanoscale memory devices, and molecular devices were selected. Though the priority was on memory devices and new types of transistors, molecular devices were included in this version considering the impact of this technology.

The time span of the roadmap is important in order to cover the technology which may be realized in a certain period of time. However, with regard to nanoelectronics development, little information on the average technology development period is available at this stage. Thus TC 113 set the span of the roadmap up until the year 2020 to show the starting point of standardization tasks and the end of activity.

As the format should give insights and detailed information to the user of the roadmap, the Gantt chart format was used, including photos (see Figure 1). When a new version of the roadmap is prepared, TC 113 will develop a new format in parallel, which can give more accurate information to users.



Figure 1 - Roadmap format

IEC NANOELECTRONICS STANDARDIZATION ROADMAP

1 Scope

This Technical Report covers nanomaterials and nanoscale devices. To achieve consensus more quickly when building the roadmap, an ICT "More Moore" area has been adopted for the priority standardization items of this first version, as shown in Table 1.

Table 1 – Categories and detail potential products

Ca	tegories	Detail potential products	Version 1
	Zero-dimensional nanomaterial	Nanoparticles/Nanopowders Quantum dot	√ √
	One-dimensional nanomaterial	Carbon nanotube Nanowire (III-V, II-VI, ZnO)	√
Nanomaterials	Two-dimensional nanomaterial	Nanofunctional thin film Nanostructural film Graphene	V
	Three-dimensional nanomaterial	Nanopore materials Nanocomposites	
	Nanoelectronic devices	Nanoscale non-volatile memory devices 1- and 3-dimensional nanoscale transistors Single electron transistor Nanoscale logic devices Nanoscale interconnection Post-CMOS signal processing	\ \ \ \
Nanoscale devices	Nanoscale optical devices	Silicon optical devices Photonic crystal optical devices All-optical logic devices Quantum dot optical devices	
ivalioscale devices	Nanoscale magnetic devices	Highly integrated memory devices High-speed magnetic logic devices	√ √
	Molecular devices	Molecular logic device Molecular memory device Molecular sensors Molecular mechanics devices Molecular optical devices	1
	Nanomaterials-based flexible devices	Nanomaterials-based flexible devices Nanomaterials-based displays	
Nanofabrication processes,	Nanofabrication process	Nano lithography Self-assembly	
equipment measurement	Nanoscale metrology and simulation	SPM	